MOSFET – Single P-Channel, Small Signal, SOT-1123, 1.0 x 0.6 mm

-20 V, -200 mA

Features

- Single P-Channel MOSFET
- \bullet Offers a Low $R_{DS(on)}$ Solution in the Ultra Small 1.0 x 0.6 mm Package
- 1.5 V Gate Voltage Rating
- Ultra Thin Profile (< 0.5 mm) Allows It to Fit Easily into Extremely Thin Environments such as Portable Electronics.
- This is a Pb-Free Device

Applications

- High Side Switch
- High Speed Interfacing
- Optimized for Power Management in Ultra Portable Equipment

MAXIMUM RATINGS (T_J = 25°C unless otherwise specified)

Para	Symbol	Value	Unit			
Drain-to-Source Voltage	V _{DSS}	-20	V			
Gate-to-Source Voltag	е		V_{GS}	±8	V	
Continuous Drain Stead		$T_A = 25^{\circ}C$		-150		
Current (Note 1)	State	$T_A = 85^{\circ}C$	I_{D}	-110	mA	
	t ≤ 5 s	$T_A = 25^{\circ}C$		-200		
Power Dissipation				-125		
(Note 1)	State	$T_A = 25^{\circ}C$	P_{D}		mW	
	t ≤ 5 s			-200		
Pulsed Drain Current	I _{DM}	-600	mA			
Operating Junction and	T _J ,	-55 to	°C			
	T _{STG}	150				
Source Current (Body D	IS	-200	mA			
Lead Temperature for S (1/8" from case for 1	T_L	260	°C			

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

 Surface-mounted on FR4 board using the minimum recommended pad size, or 2 mm², 1 oz Cu.

1

2. Pulse Test: pulse width $\leq\!300~\mu\text{s},$ duty cycle $\leq\!2\%$



ON Semiconductor®

http://onsemi.com

V _{(BR)DSS}	R _{DS(ON)} MAX	I _D Max	
-20 V	3.5 Ω @ -4.5 V		
	4.0 Ω @ -2.5 V	0.00 4	
	5.5 Ω @ -1.8 V	–0.20 A	
	7.0 Ω @ -1.5 V		



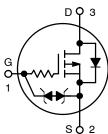
MARKING DIAGRAM



= Specific Device Code
 (Rotated 90° Clockwise)

M = Date Code

P-Channel MOSFET



ORDERING INFORMATION

Device	Package	Shipping [†]		
NTNUS3171PZT5G	SOT-1123 (Pb-Free)	8000/Tape & Reel		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Max	Unit
Junction-to-Ambient - Steady State (Note 3)	$R_{ heta JA}$	1000	°C/W
Junction-to-Ambient - t = 5 s (Note 3)	$R_{ hetaJA}$	600	

^{3.} Surface-mounted on FR4 board using the minimum recommended pad size, or 2 mm², 1 oz Cu.

ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS	•						
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$		-20			V
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 \text{ V}, V_{DS} = -5.0 \text{ V}$ $T_J = 25^{\circ}\text{C}$				-50	
		$V_{GS} = 0 \text{ V}, V_{DS} = -5.0 \text{ V}$	T _J = 85°C			-100	nA
		$V_{GS} = 0 \text{ V}, V_{DS} = -16 \text{ V}$	T _J = 25°C			-200	
Gate-to-Source Leakage Current	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 5.0 \text{ V}$				±100	nA
ON CHARACTERISTICS (Note 4)	•	•		•	•		
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}$, $I_D = -2$	250 μΑ	-0.4	-0.7	-1.0	V
Drain-to-Source On Resistance	R _{DS(ON)}	$V_{GS} = -4.5 \text{ V}, I_D = -100 \text{ mA}$			2.0	3.5	Ω
		$V_{GS} = -2.5 \text{ V}, I_D = -50 \text{ mA}$			2.6	4.0	
		V _{GS} = -1.8 V, I _D = -20 mA			3.4	5.5	
		$V_{GS} = -1.5 \text{ V}, I_D = -10 \text{ mA}$ $V_{GS} = -1.2 \text{ V}, I_D = -1.0 \text{ mA}$			4.0	7.0	
					6.0		
Forward Transconductance	9FS	V _{DS} = -5.0 V, I _D = -125 mA			0.26		S
Source-Drain Diode Voltage	V_{SD}	$V_{GS} = 0 \text{ V, } I_{S} = -200 \text{ mA}$		-0.5		-1.4	V
CHARGES, CAPACITANCES AND GATE	RESISTANCE	-					
Input Capacitance	C _{ISS}				13		
Output Capacitance	C _{OSS}	$f = 1 \text{ MHz}, V_{GS} = 0 \text{ V}$ $V_{DS} = -15 \text{ V}$			3.4		pF
Reverse Transfer Capacitance	C _{RSS}	100			1.6		1
SWITCHING CHARACTERISTICS, V _{GS} =	4.5 V (Note 4)			-	-		
Turn-On Delay Time	t _{d(ON)}				30		
Rise Time	t _r	V_{GS} = -4.5 V, V_{DD} = -15 V, I_{D} = -200 mA, R_{G} = 2.0 Ω			56		
Turn-Off Delay Time	t _{d(OFF)}				196		ns
Fall Time	t _f				145		

^{4.} Switching characteristics are independent of operating junction temperatures

TYPICAL CHARACTERISTICS

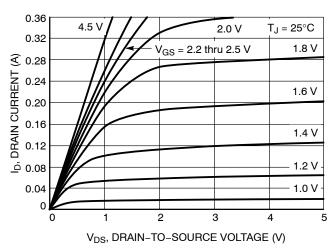


Figure 1. On-Region Characteristics

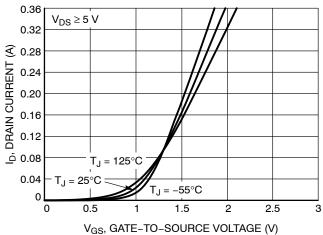
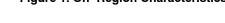


Figure 2. Transfer Characteristics



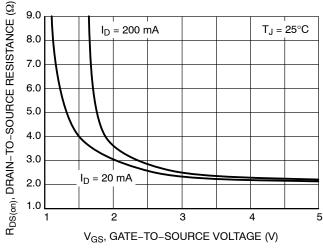


Figure 3. On-Resistance vs. Gate Voltage

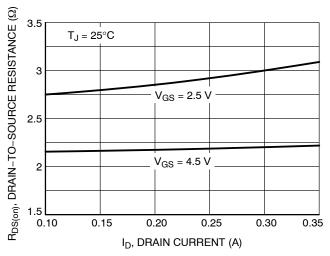


Figure 4. On-Resistance vs. Drain Current and Gate Voltage

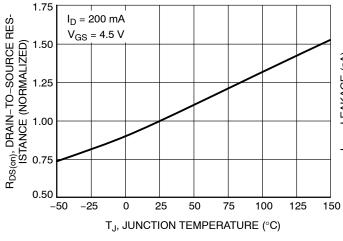


Figure 5. On–Resistance Variation with Temperature

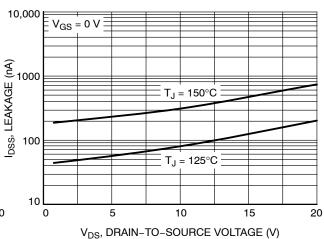
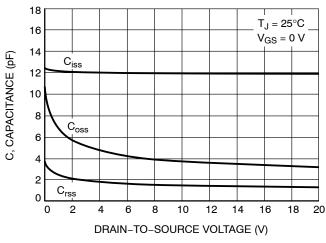


Figure 6. Drain-to-Source Leakage Current vs. Voltage

TYPICAL CHARACTERISTICS



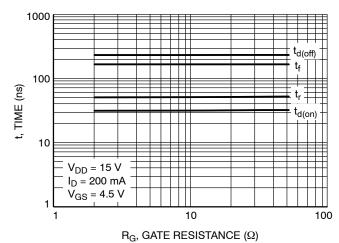


Figure 7. Capacitance Variation

Figure 8. Resistive Switching Time Variation vs. Gate Resistance

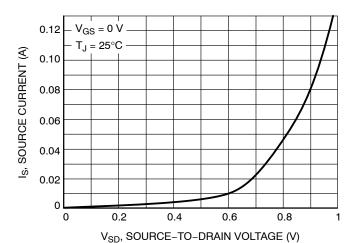
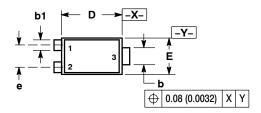
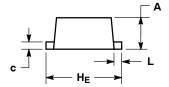


Figure 9. Diode Forward Voltage vs. Current

PACKAGE DIMENSIONS

SOT-1123 CASE 524AA-01 **ISSUE B**





NOTES:

- NOTES:

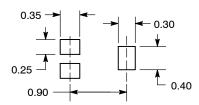
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETERS.

 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.34	0.37	0.40	0.013	0.015	0.016
b	0.15	0.22	0.28	0.006	0.009	0.011
b1	0.10	0.15	0.20	0.004	0.006	800.0
С	0.07	0.12	0.17	0.003	0.005	0.007
D	0.75	0.80	0.85	0.030	0.031	0.033
Е	0.55	0.60	0.65	0.022	0.024	0.026
е	0.35		0.40	0.014		0.016
HE	0.95	1.00	1.05	0.037	0.039	0.041
L	0.05	0.10	0.15	0.002	0.004	0.006

SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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